

DATA SHEET UNIVISO – UTS10Z8Bxx

10.3Gbps SFP+ BIDI Transceiver, Single Mode,80km Reach TX1490nm / RX1550nm (TX1550nm / RX1490nm)

UTS10Z8Bxx are hot-pluggable 3.3V Small-Form-Factor transceiver modules. They are designed expressly for high-speed communication applications that require rates up to 11.1Gb/s, they are designed to be compliant with SFF-8472 SFP+ MSA. The module data link up to 80km in 9/125um single mode fiber.

Product Features

- Supports 11.1Gb/s bit rates
- Hot-pluggable SFP+ footprint
- Up to 80km for SMF transmission
- 1490nm EML laser and APD receiver for UTS10Z8B45 1550nm EML laser and APD receiver for UTS10Z8B54
- Compliant with SFP+ MSA with single LC receptacle
- Compatible with RoHS
- Single +3.3V power supply
- Power dissipation<1.8W
- 2-wire interface with integrated Digital Diagnostic monitoring
- EEPROM with Serial ID Functionality
- Operating case temperature: Standard: -5 to +70°C Industrial: -40 to +85°C

Applications

• 10GBASE-BX 10.3125Gb/s Ethernet

Ordering Information

	Specifications (Per Channel)										
Part. No	Pack	Rate	Тх	Ро	RX	Sen	Temp	Reach	DDM		
	(Gbps) (nm) (dBm)		(dBm)	(°C)	(km)						
UTS10Z8B45	SFP+	10.3	1490	0~4	APD	<-23	0~70	80	Y		
UTS10Z8B54	SFP+	10.3	1550	-1~3	APD	<-23	0~70	80	Y		
UTS10Z8B45I	SFP+	10.3	1490	0~4	APD	<-23	-40~85	80	Y		
UTS10Z8B54I	SFP+	10.3	1550	-1~3	APD	<-23	-40~85	80	Y		
For More Information:	-										
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General Specifications

Parameter	Symbol	Min	Тур	Max	Unit	Remarks
Data Rate per Lane	DR	9.95	10.3	11.1	Gbps	
Operating Temperature	T _{OP}	0		70	°C	
Storage Temperature	T _{STO}	- 40		85	°C	
Power Supply Current	ICC			550	mA	
Input Voltage	V _{CC}	3.14	3.3	3.46	V	
Maximum Voltage	V _{MAX}	- 0.3		4	V	

Optical Characteristics – Transmitter

 $V_{cc}=3.14V$ to 3.46V, $T_c=-5^{\circ}C$ to 70°C

Parameter	Symbol	Min	Тур	Max	Unit	Remarks
Average Launch Dower each lane	Dava	0		4	dBm	UTS10Z8B45
Average Launch Power each lane	Pavg	-1		3	dBm	UTS10Z8B54
Transmitter and Dispersion Penalty each lane	TDP			4.3	dB	
Mayolongth Assignment	λ0	1480		1500	nm	UTS10Z8B45
Wavelength Assignment		1540		1560	nm	UTS10Z8B54
Spectral Width(-20dB)	Δλ			0.3	nm	
Extinction Ratio	ER	7.5			dB	
Optical Return Loss Tolerance	ORL			12	dBm	
Output Eye Diagram		Corr	pliant with IEE	E802.3bm eye r	nask	

Optical Characteristics – Receiver V_{cc} =3.14V to 3.46V, T_c =-5°C to 70°C

Parameter	Symbol	Min	Тур	Мах	Unit	Remarks
Rx Sensitivity per lane	S			-23	dBm	1
Paggiver Weyelength	١.	1540		1560	nm	UTS10Z8B45
Receiver Wavelength	λ_0	1480		1500	nm	UTS10Z8B54
Optical Power Input Overload	P _{in-max}	2.4			dBm	
Receiver Reflectance				-12	dB	
LOS Assert	P_{LOS_A}	- 38			dBm	
LOS De-Assert	P_{LOS_D}			– 25	dBm	
LOS Hysteresis		0		5	dB	

Notes:

1. Measured with a PRBS 2^{31} -1 test pattern, @10.312Gb/s, BER<10- 12 .

Electrical Characteristics

 $V_{CC}{=}3.14V$ to 3.46V, $T_{C}{=}{-}5^{\circ}\!C$ to $70^{\circ}\!C$

Confidential



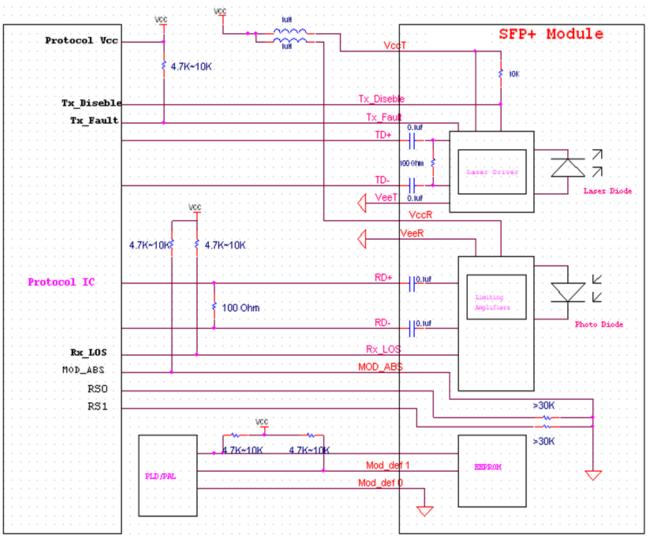
UTS10Z8Bxx

Symbol	Min	Тур	Max	Unit	Remarks
Vcc	3.14	3.3	3.46	mV	
lcc			550	mA	
Rin		100		Ω	1
Vin,pp	180		1200	mV	
VinT	-0.3		4.0	V	
Vout,pp	300		850	mV	2
	-0.3		4.0	V	
	Vcc Icc Rin Vin,pp VinT	Vcc 3.14 Icc	Vcc 3.14 3.3 lcc	Vcc 3.14 3.3 3.46 Icc 550 550 Rin 100 1200 Vin,pp 180 1200 VinT -0.3 4.0 Vout,pp 300 850	Vcc 3.14 3.3 3.46 mV Icc 550 mA Rin 100 Ω Vin,pp 180 1200 mV VinT -0.3 4.0 V Vout,pp 300 850 mV

Notes:

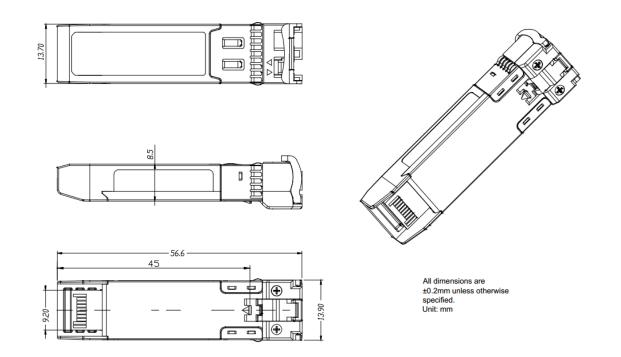
- 1. Connected directly to TX data input pins. AC coupled thereafter.
- 2. Into 100Ω ohms differential termination

Block Diagram

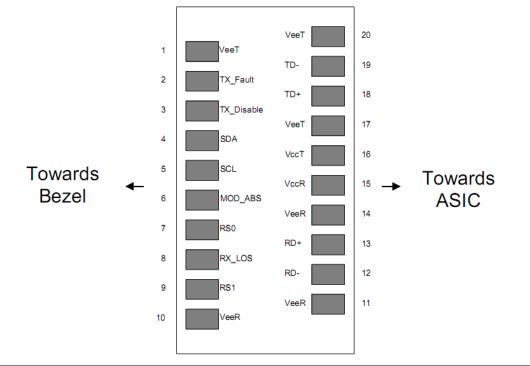




Dimensions



Electrical Pad Layout



	Notes
1 VEET Transmitter Ground	1



UTS10Z8Bxx

2	TX FAULT	Transmitter Fault Indication	2
3	TX DISABLE	Transmitter Disable	3
4	SDA	2-wire Serial Interface Data Line	4
5	SCL	2-wire Serial Interface Clock Line	4
6	MOD_ABS	Module Absent. Grounded within the module	4
7	RS0	Rate Select 0	5
8	LOS	Loss of Signal	6
9	RS1	Not Connected	1
10	VEER	Receiver ground	1
11	V _{EER}	Receiver ground	1
12	RD-	Inv. Received Data Out	
13	RD+	Received Data Out	
14	V _{EER}	Receiver ground	1
15	V _{CCR}	Receiver Power Supply	
16	Vcct	Transmitter Power Supply	
17	VEET	Transmitter Ground	1
18	TD+	Transmit Data In	
19	TD-	Inv. Transmit Data In	
20	VEET	Transmitter Ground	1

Notes:

Plug Seq.: Pin engagement sequence during hot plugging.

- 1) Circuit ground is internally isolated from chassis ground.
- 2) TFAULT is an open collector/drain output, which should be pulled up with a 4.7k 10k Ohms resistor on the host board if intended for use. Pull up voltage should be between 2.0V to Vcc + 0.3V.A high output indicates a transmitter fault caused by either the TX bias current or the TX output power exceeding the preset alarm thresholds. A low output indicates normal operation. In the low state, the output is pulled to <0.8V.</p>
- 3) Laser output disabled on TDIS >2.0V or open, enabled on TDIS <0.8V.
- Should be pulled up with 4.7kΩ- 10kΩ host board to a voltage between 2.0V and 3.6V. MOD_ABS pulls line low to indicate module is plugged in.
- 5) Internally pulled down per SFF-8431 Rev 4.1.
- 6) LOS is open collector output. It should be pulled up with $4.7k\Omega 10k\Omega$ on host board to a voltage between 2.0V and 3.6V. Logic 0 indicates normal operation; logic 1 indicates loss of signal.

References

- 1. IEEE standard 802.3. IEEE Standard Department, 2005.
- 2. Small Form Factor Pluggable (SFP) Transceiver Multi-Source Agreement (MSA), September 2000.